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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR 2SK4069

SWITCHING N-CHANNEL POWER MOSFET

DESCRIPTION

The 2SK4069 is N-channel MOS FET device that features a low on-state resistance and excellent switching characteristics, and designed for low voltage high current applications such as DC/DC converter with synchronous rectifier.

FEATURES

<R>

• Low on-state resistance

 $R_{DS(on)1} = 12 \text{ m}\Omega \text{ MAX}. \text{ (Vgs} = 10 \text{ V, ID} = 15 \text{ A)}$

- Low Q_{GD}: Q_{GD} = 3.2 nC TYP.
- 4.5 V drive available

ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK4069(1)-S27-AY Note	TO-251 (MP-3-b)
2SK4069-ZK-E1-AY Note	TO-252 (MP-3ZK)
2SK4069-ZK-E2-AY Note	TO-252 (MP-3ZK)

Note Pb-free (This product does not contain Pb in external electrode.)

(TO-251)



TO-252\



ABSOLUTE MAXIMUM RATINGS (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	Voss	25	V
Gate to Source Voltage (Vps = 0 V)	Vgss	±20	V
Drain Current (DC) (Tc = 25°C)	I _{D(DC)}	Α	
Drain Current (pulse) Note1	I _{D(pulse)}	±120	Α
Total Power Dissipation (Tc = 25°C)	P _{T1}	21	W
Total Power Dissipation	P _{T2}	1.0	W
Channel Temperature	T_ch	150	°C
Storage Temperature	T_{stg}	-55 to +150	°C
Single Avalanche Current Note2	las	18	Α
Single Avalanche Energy Note2	Eas	32.4	mJ

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Starting T_{ch} = 25°C, V_{DD} = 12 V, R_G = 25 Ω , V_{GS} = 20 \rightarrow 0 V, L = 100 μ H

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Document No. D18032EJ3V0DS00 (3rd edition) Date Published March 2007 NS CP(K) Printed in Japan

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ELECTRICAL CHARACTERISTICS (TA = 25°C)

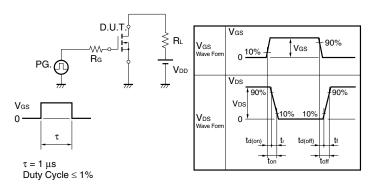
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 25 V, V _{GS} = 0 V			10	μА
Gate Leakage Current	Igss	Vgs = ±20 V, Vps = 0 V			±100	nA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5	2.0	2.5	V
Forward Transfer Admittance Note	yfs	V _{DS} = 10 V, I _D = 7.5 A	5	10		S
Drain to Source On-state Resistance Note	RDS(on)1	Vgs = 10 V, lp = 15 A		9.4	12	mΩ
	RDS(on)2	Vgs = 4.5 V, ID = 15 A		15	21	mΩ
Input Capacitance	Ciss	V _{DS} = 10 V		860		pF
Output Capacitance	Coss	Vos = 0 V f = 1 MHz		255		pF
Reverse Transfer Capacitance	Crss			90		pF
Turn-on Delay Time	td(on)	V _{DD} = 12 V, I _D = 30 A		14/7.5		ns
Rise Time	t r	Vgs = 4.5 V/12 V		13/4.2		ns
Turn-off Delay Time	t _{d(off)}	$R_G = 3 \Omega$		1.9/24		ns
Fall Time	tf			14/4.4		ns
Total Gate Charge	Q _{G1}	V _{DD} = 12 V ,V _{GS} = 12 V, I _D = 30 A		17		nC
Total Gate Charge	Q _{G2}	V _{DD} = 12 V ,V _{GS} = 4.5 V, I _D = 30 A		6.7		nC
Gate to Source Charge	Qgs	V _{DD} = 12 V , I _D = 30 A		2.4		nC
Gate to Drain Charge	Q _{GD}			3.2		nC
Gate Resistance	Rg			1.5		Ω
Body Diode Forward Voltage Note	V _{F(S-D)}	IF = 30 A, VGS = 0 V		0.9	1.5	V
Reverse Recovery Time	trr	IF = 30 A, VGS = 0 V		29		ns
Reverse Recovery Charge	Qrr	di/dt = 100 A/μs		20		nC

Note Pulsed

TEST CIRCUIT 1 AVALANCHE CAPABILITY

$V_{GS} = 20 \rightarrow 0 \text{ V}$ $PG. \longrightarrow 50 \Omega$ $V_{DD} \longrightarrow 10 \text{ PG}$ $V_{DD} \longrightarrow 10 \text{ PG}$

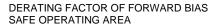
TEST CIRCUIT 2 SWITCHING TIME

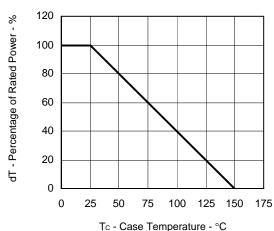


TEST CIRCUIT 3 GATE CHARGE

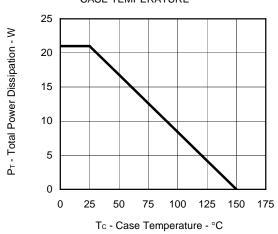
Starting Tch

TYPICAL CHARACTERISTICS (TA = 25°C)

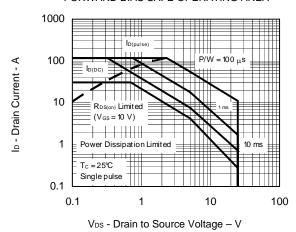




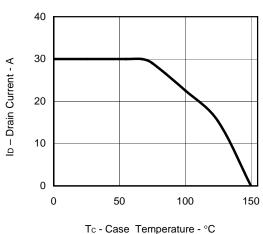
TOTAL POWER DISSIPATION vs. CASE TEMPERATURE



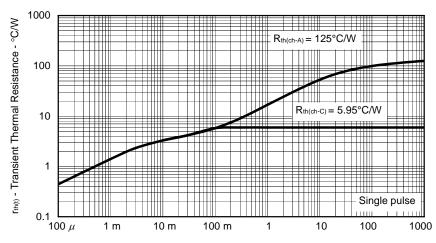
FORWARD BIAS SAFE OPERATING AREA



DRAIN CURRENT vs CASE TEMPERATURE

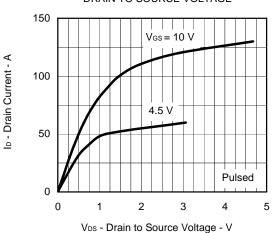


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

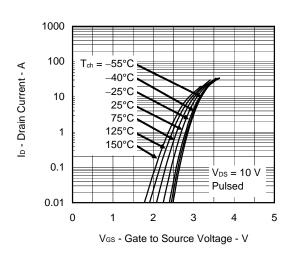


PW - Pulse Width - s

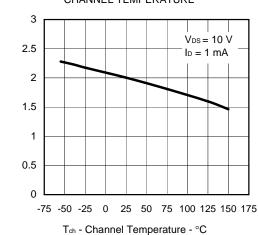
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



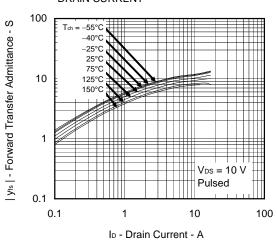
FORWARD TRANSFER CHARACTERISTICS



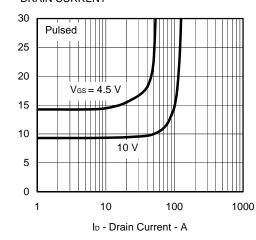
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



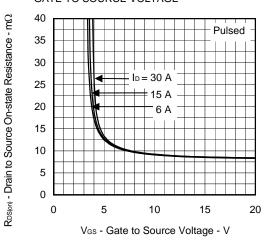
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

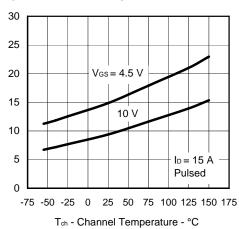


R_{DS(on)} - Drain to Source On-state Resistance - mΩ

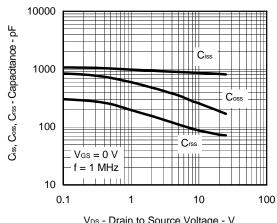
Ves(off) - Gate Cut-off Voltage - V

RDS(m) - Drain to Source On-state Resistance - m\Omega

DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE

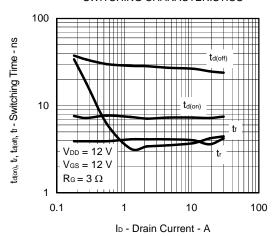


CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE

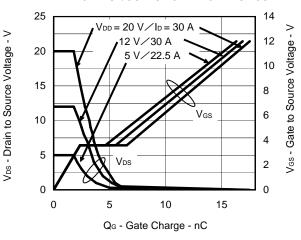


V_{DS} - Drain to Source Voltage - V

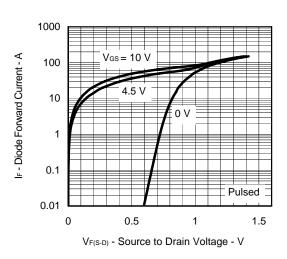
SWITCHING CHARACTERISTICS



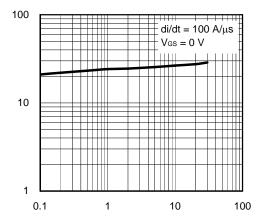
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



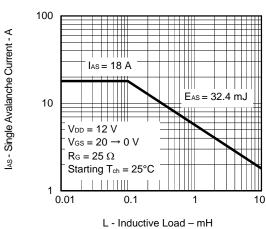
REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



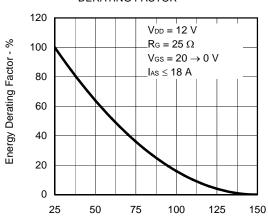
IF - Diode Forward Current - A

trr - Reverse Recovery Time - ns

SINGLE AVALANCHE CURRENT vs. INDUCTIVE LOAD



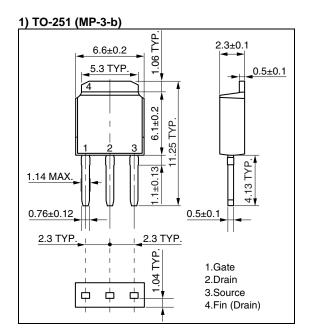
SINGLE AVALANCHE ENERGY DERATING FACTOR

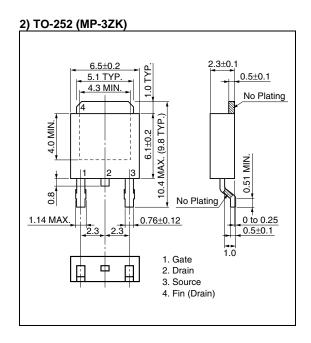


Starting Tch - Starting Channel Temperature - °C

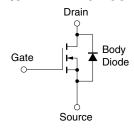
PACKAGE DRAWINGS (Unit: mm)

<R>





EQUIVALENT CIRCUIT



Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

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